April 2011



FDH055N15A N-Channel PowerTrench[®] MOSFET 150V, 167A, 5.9mΩ

Features

- R_{DS(on)} = 4.8mΩ (Typ.)@ V_{GS} = 10V, I_D = 120A
- · Fast Switching Speed
- · Low Gate Charge
- High Performance Trench Technology for Extremely Low $R_{\text{DS}(\text{on})}$
- High Power and Current Handling Capability
- RoHS Compliant

Description

This N-Channel MOSFET is produced using Fairchild Semiconductor's advanced PowerTrench process that has been especially tailored to minimize the on-state resistance and yet maintain superior switching performance.

Application

- DC to DC Converters
- Synchronous Rectification for Server/Telecom PSU
- Battery Charger
- · AC motor drives and Uninterruptible Power Supplies
- Off-line UPS





MOSFET Maximum Ratings T_C = 25°C unless otherwise noted

Symbol		Parameter		Ratings	Units	
V _{DSS}	Drain to Source Voltage		150	V		
V _{GSS}	Gate to Source Voltage			±20	V	
I _D	Drain Current	- Continuous (T _C = 25 ^o	C, Silicon Limited)	167*	Α	
		- Continuous (T _C = 100	^o C, Silicon Limited)	118		
		- Continuous (Tc = 25°	C, Package Limited)	156		
I _{DM}	Drain Current	- Pulsed	(Note 1)	668	Α	
E _{AS}	Single Pulsed Avalanche Energy (Note 2,6)		(Note 2,6)	835	mJ	
dv/dt	Peak Diode Recovery dv/dt (Note 3)		(Note 3)	6.0	V/ns	
P _D	Power Dissipation	(T _C = 25 ^o C)		429	W	
		- Derate above 25°C		2.86	W/ºC	
T _J , T _{STG}	Operating and Storage Temperature Range			-55 to +175	°C	
TL	Maximum Lead Temperature for Soldering Purpose, 1/8" from Case for 5 Seconds			300	°C	

The superal Characteristics

Thermal Characteristics

Symbol	Parameter	Ratings	Units
$R_{ ext{ heta}JC}$	Thermal Resistance, Junction to Case	0.35	
$R_{\theta CS}$	Thermal Resistance, Case to Heat Sink (Typical)	0.24	°C/W
$R_{ hetaJA}$	Thermal Resistance, Junction to Ambient	40	

	Device Marking Device Pack		Packag	age Reel Size Tap		e Width		Quantit	y	
	<u> </u>		TO-247	7	-		-		30	
Symbol	I Char	acteristics T _c =	25ºC unless	otherwise not	ted					
Oymbol		Parameter		Те	st Conditions	6	Min.	Тур.	Max.	Units
Off Charac	teristic	S								
BV _{DSS}	Drain to	Source Breakdown Vo	oltage	I _D = 250μA,	V _{GS} = 0V		150	-	-	V
ΔBV_{DSS} ΔT_J		reakdown Voltage Temperature oefficient		$I_D = 250\mu$ A, Referenced to 25° C			-	0.1	-	V/ºC
I _{DSS}	Zero Ga	o Gate Voltage Drain Current		V_{DS} = 120V, V_{GS} = 0V V_{DS} = 120V, T_{C} = 150°C			-	-	1 500	μA
I _{GSS}	Gate to	Body Leakage Curren	t	$V_{GS} = \pm 20V$, V _{DS} = 0V		-	-	±100	nA
				_					1	1
On Charac		-							T	
V _{GS(th)}	Gate Th	nreshold Voltage		$V_{GS} = V_{DS}$,			2.0	-	4.0	V
R _{DS(on)}	Static D	rain to Source On Res	istance	V_{GS} = 10V,			-	4.8	5.9	mΩ
9FS	Forward	d Transconductance		V_{DS} = 10V,	I _D = 120A	(Note 4)	-	219	-	S
Dynamic C	haracte	vietice								
•								7400	0445	-
C _{iss}		apacitance		V _{DS} = 75V,	$V_{CS} = 0V$	-	-	7100	9445	pF
C _{oss}		Capacitance		f = 1MHz	66	-	-	664	885	pF
C _{rss}		e Transfer Capacitance					-	23	-	pF
C _{oss(er)}	0,	Related Output Capac	sitance	V _{DS} = 75V,	$V_{GS} = 0V$		-	1159	-	pF
Q _{g(tot)}		Gate Charge at 10V o Source Gate Charge		V _{DS} = 75V, I _D = 120A		-	92	120	nC	
Q _{gs}						-	31	-	nC	
Q _{gs2}		harge Threshold to Plat	teau	V _{GS} = 10V (Note 4,5)		-	15	-	nC	
Q _{gd}		Drain "Miller" Charge				-	16	-	nC	
ESR	Equivale	ent Series Resistance(G-S)	Drain Open			-	1.2	-	Ω
Switching	Charac	teristics								
t _{d(on)}	Turn-On	Delay Time					-	35	80	ns
t _r	Turn-On	Rise Time		V _{DD} = 75V,	I _D = 120A	-	-	67	144	ns
t _{d(off)}	Turn-Off Delay Time			$V_{GS} = 10V, R_{GEN} = 4.7\Omega$		-	71	152	ns	
t _f	Turn-Off	f Fall Time		(Note 4,5)			-	21	52	ns
Drain-Sou		de Characteristic	6			1				
I _s		m Continuous Drain to		e Forward Cu	rrent		-	-	167*	A
I _{SM}		m Pulsed Drain to Sou					-	-	668	A
		Source Diode Forward		V _{GS} = 0V, I _S			-	-	1.25	V
		Recovery Time			_{SD} = 120A, V _D	o = 75V	-	105	-	ns
V _{SD}	11646136	,		$dI_{\rm F}/dt = 100$		(Note 4)	-	342	_	nC





















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